# **inter<sub>sil</sub>**

# Radiation Hardened Adjustable Positive Voltage Regulator

# HS-117RH, HS-117EH

The Radiation Hardened HS-117RH, HS-117EH are adjustable positive voltage linear regulator capable of operating with input voltages up to 40VDC. The output voltage is adjustable from 1.2V to 37V with two external resistors. The device is capable of sourcing from 5mA to 1.25A<sub>PEAK</sub> (0.5 A<sub>PEAK</sub> for the TO-39 package). Protection is provided by the on-chip thermal shutdown and output current limiting circuitry.

The Intersil HS-117RH, HS-117EH has advantages over other industry standard types, in that circuitry is incorporated to minimize the effects of radiation and temperature on device stability.

Constructed with the Intersil dielectrically isolated Rad Hard Silicon Gate (RSG) process, the HS-117RH, HS-117EH are immune to single event latch-up and has been specifically designed to provide highly reliable performance in harsh radiation environments.

Specifications for Rad Hard QML devices are controlled by the Defense Logistics Agency (DLA). The SMD numbers listed here must be used when ordering.

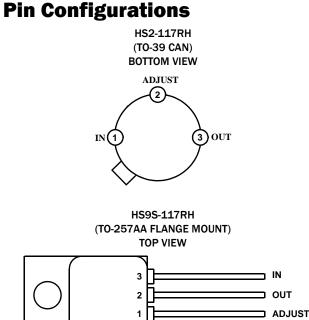
Detailed electrical specifications for the HS-117RH, HS-117EH are contained in <u>SMD 5962-99547</u>. A "hot-link" is provided on our website for downloading.

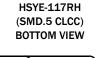
# **Features**

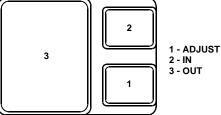
- Electrically Screened to DLA SMD # 5962-99547
- QML Qualified per MIL-PRF-38535 Requirements
- Radiation Environment
  - 300 krad (Si) (Max)
  - Latch-up Immune
- Superior Temperature Stability
- Overcurrent and Overtemperature Protection

## Applications

- Adjustable Linear Voltage Regulators
- Adjustable Linear Current Regulator







NOTE: No current JEDEC outline for the SMD.5 package. Refer to SMD for package dimensions. The T0-257 is a totally isolated metal package

# **Ordering Information**

ORDERING NUMBER	INTERNAL MKT. NUMBER	TEMP. RANGE (°C)	PACKAGE	PKG DWG. #
5962F9954702VUC	HS2-117EH-Q	-55 to +125	3 LD METAL CAN	T3.C
5962F9954702V9A	HS0-117EH-Q	-55 to +125	DIE	
5962F9954702VXC	HS9S-117EH-Q	-55 to +125	3 LD TO-257	T3.D
5962F9954702VYC	HSYE-117EH-Q	-55 to +125	3 PAD LCC	J3.A
5962F9954701VUC	HS2-117RH-Q	-55 to +125	3 LD METAL CAN	T3.C
5962F9954701QUC	HS2-117RH-8	-55 to +125	3 LD METAL CAN	T3.C
5962F9954701VXC	HS9S-117RH-Q	-55 to +125	3 LD TO-257	T3.D
5962F9954701QXC	HS9S-117RH-8	-55 to +125	3 LD TO-257	T3.D
5962F9954701VYC	HSYE-117RH-Q	-55 to +125	3 PAD LCC	J3.A
5962F9954701QYC	HSYE-117RH-8	-55 to +125	3 PAD LCC	J3.A
HS2-117RH/Proto	HS2-117RH/Proto	-55 to +125	3 LD TO-257	T3.C
HS9S-117RH/Proto	HS9S-117RH/Proto	-55 to +125	3 LD TO-257	T3.D
HSYE-117RH/Proto	HSYE-117RH/Proto	-55 to +125	3 PAD LCC	
5962F9954701QUC	HS2-117RH-8S9000	-55 to +125	3 LD METAL CAN	T3.C
5962F9954701VXC	HS9S-117RH-QS9000	-55 to +125	3 LD TO-257	T3.D
5962F9954701VYC	HSYE-117RH-QS9000	-55 to +125	3 PAD LCC	J3.A
5962F9954701VYC	HSYE-117RH-QS9002	-55 to +125	3 PAD LCC	J3.A

NOTE:

1. These Intersil Pb-free Hermetic packaged products employ 100% Au plate - e4 termination finish, which is RoHS compliant and compatible with both SnPb and Pb-free soldering operations.

# **Die Characteristics**

#### **DIE DIMENSIONS**

2616mm x 2794mm (103 mils x 110 mils) 483mm ±25.4mm (19 mils ±1 mil)

### **INTERFACE MATERIALS**

#### Glassivation

Type: Silox (SiO<sub>2</sub>) Thickness: 8.0kÅ ±1.0kÅ

#### **Top Metallization**

Type: AlSiCu Thickness: 16.0kÅ ±2kÅ

#### Substrate

Radiation Hardened Silicon Gate, Dielectric Isolation

#### **Backside Finish**

Gold

#### **ASSEMBLY RELATED INFORMATION**

Substrate Potential

Unbiased (DI)

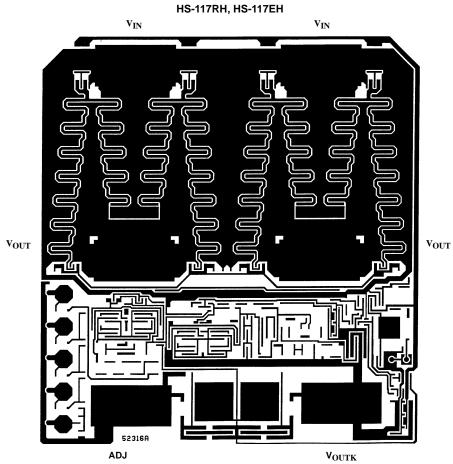
#### **ADDITIONAL INFORMATION**

Worst Case Current Density  $<2.0 \times 10^5 \text{ A/cm}^2$ 

#### **Transistor Count**

95

# **Metallization Mask Layout**



For additional products, see www.intersil.com/product\_tree

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